www.*Microsemi*.co

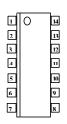


Switching Diode Array Steering Diode TVS Array[™]

DESCRIPTION

These low capacitance diode arrays are multiple, discrete, isolated junctions fabricated by a planar process and mounted in a 14-PIN package for use as steering diodes protecting up to ten I/O ports from ESD, EFT, or surge by directing them either to the positive side of the power supply line or to ground (see figure 1). An external TVS diode may be added between the positive supply line and ground to prevent overvoltage on the supply rail. They may also be used in fast switching core-driver applications. This includes computers and peripheral equipment such as magnetic cores, thin-film memories, plated-wire memories, etc., as well as decoding or encoding applications. These arrays offer many advantages of integrated circuits such as high-density packaging and improved reliability. This is a result of fewer pick and place operations, smaller footprint, smaller weight, and elimination of various discrete packages that may not be as user friendly in PC board mounting.

SWITCHING AND STEERING ARRAY



Top Viewing Pin Layout

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

FEATURES

- 20 Diode Array / protects 10 lines
- Molded 14-Pin SOIC Package
- UL 94V-0 Flammability Classification
- Low Capacitance 1.5 pF per diode
- Switching speeds less than 5 ns
- IEC 61000-4 compatible

61000-4-2 (ESD): Air 15kV, contact - 8 kV

61000-4-4 (EFT): 40A - 5/50 ns 61000-4-5 (surge): 12A, 8/20 µs

APPLICATIONS / BENEFITS

- High Frequency Data Lines
- RS-232 & RS-422 Interface Networks
- Ethernet: 10 Base T
- Computer I / O Ports
- LAN
- Switching Core Drivers

MAXIMUM RATINGS

- Operating Temperature: -55°C to +150°C
 Storage Temperature: -55°C to +150°C
- Forward Surge Current: 2 Amps (8.3 ms)

12 Amps (8/20 µs)

- Continuous Forward Current: 400 mA (one diode)
- Power Dissipation (P_D): 1500 mW (total)

MECHANICAL AND PACKAGING

- Weight 0.127 grams (approximate)
- Marking: Logo, device number, date code
- Pin #1 defined by indent on top of package
- Tape & Reel packaging: 2500 pcs (STANDARD)
- Carrier tube packaging: 55 pcs

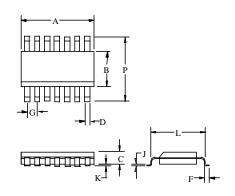
	ELECTR	LECTRICAL CHARACTERISTICS PER LINE @ 25°C Unless otherwise specified										
	PART NUMBER	BREAKDOWN VOLTAGE V _{BR} @ I _{BR} =100μA V	WORKING PEAK REVERSE VOLTAGE V _{RWM} V	CUR	KAGE RENT I _R 25°C A	CUR	KAGE RENT R 150°C	CAPACITANCE C @ 0 V pF	REVERSE RECOVERY TIME t _{rr}	FORWARD VOLTAGE V_F $I_F = 10 \text{ mA}$	FORWARD VOLTAGE V _F I _F = 100 mA	
		MIN	MAX	MAX	@V _R	MAX	@V _R	TYP	MAX	MAX	MAX	
	MMAD130	90	75	0.200	20	300	20	1.5	5.0	1.00	1.20	



Switching Diode Array Steering Diode TVS Array ™

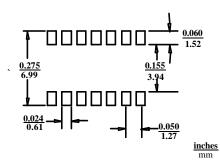
SYMBOLS & DEFINITIONS							
Symbol DEFINITION							
V _{BR} Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified curre							
 V_{RWM} Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range. V_F Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified curre 							
					I _R	Maximum Leakage Current: The maximum leakage current that will flow at the specified voltage and temperature.	
С	Capacitance: The capacitance of the TVS as defined @ 0 volts at a frequency of 1 MHz and stated in picofarads.						

OUTLINE AND CIRCUIT

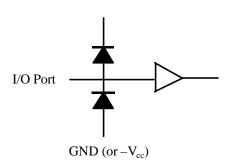


	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
A	0.336	0.344	8.53	8.74	
В	0.150	0.158	3.81	4.01	
C	0.053	0.069	1.35	1.75	
D	0.011	0.021	0.28	0.53	
F	0.016	0.050	0.41	1.27	
G	0.050	BSC	01.27 BSC		
J	0.006	0.010	0.15	0.25	
K	0.004	0.008	0.10	0.20	
L	0.189	0.206	4.80	5.23	
P	0.228	0.244	5.79	6.19	

OUTLINE

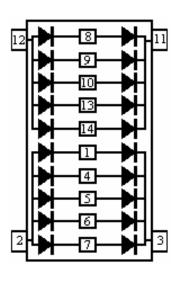






STEERING DIODE APPLICATION

figure 1



CIRCUIT CONFIGURATION